



四川旭茂微科技有限公司

Sichuan Xu Mao Micro Technology Co., Ltd

S2ABF THRU S2MBF

2.0 AMP SURFACE MOUNT SILICON RECTIFIERS

FEATURES

- * Ideal for surface mount applications
- * Easy pick and place
- * Built-in strain relief
- * Low forward voltage drop

MECHANICAL DATA

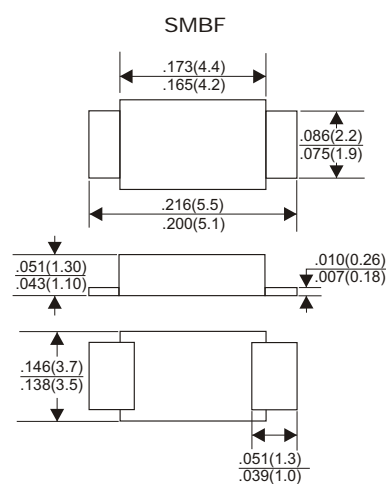
- * Case: Molded plastic
- * Epoxy: UL 94V-0 rate flame retardant
- * Metallurgically bonded construction
- * Polarity: Color band denotes cathode end
- * Mounting position: Any

VOLTAGE RANGE

50 to 1000 Volts

CURRENT

2.0 Ampere



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating 25°C ambient temperature unless otherwise specified.
Single phase half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

TYPE NUMBER	S2ABF	S2BBF	S2DBF	S2GBF	S2JBF	S2KBF	S2MBF	UNITS
Maximum Recurrent Peak Reverse Voltage	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current								
At T _L =110°C	2.0							A
Peak Forward Surge Current, 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	60							A
Maximum Instantaneous Forward Voltage at 2.0A	1.10							V
Maximum DC Reverse Current Ta=25°C	5.0							μA
at Rated DC Blocking Voltage Ta=125°C	200							μA
Typical Junction Capacitance (Note1)	30							pF
Typical Thermal Resistance R _{JL} (Note 2)	16							°C/W
Operating and Storage Temperature Range T _J , T _{stg}	-65 — +150							°C

NOTES:

1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
2. Thermal Resistance Junction to Lead.



RATING AND CHARACTERISTIC CURVES (S2ABF THRU S2MBF)

FIG.1-TYPICAL FORWARD CHARACTERISTICS

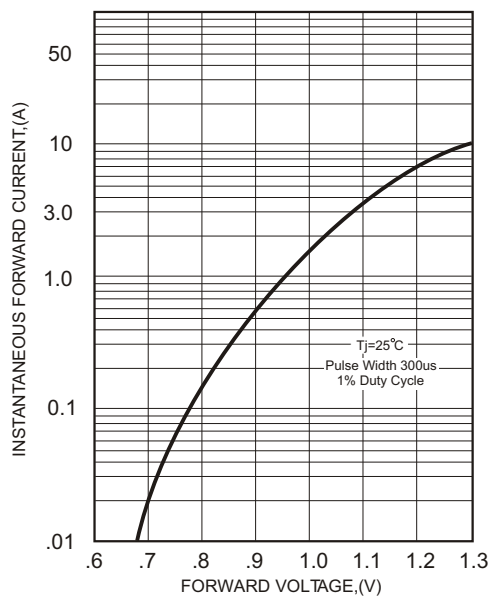


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

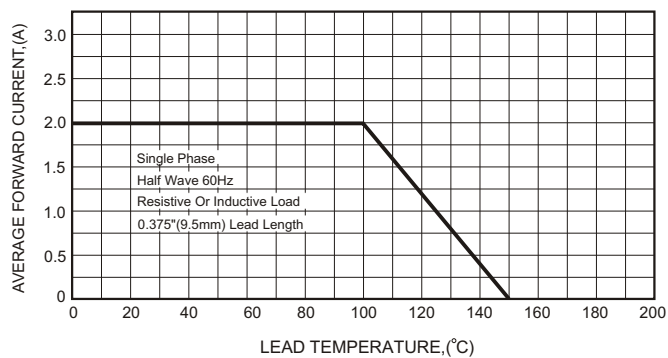


FIG.4-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

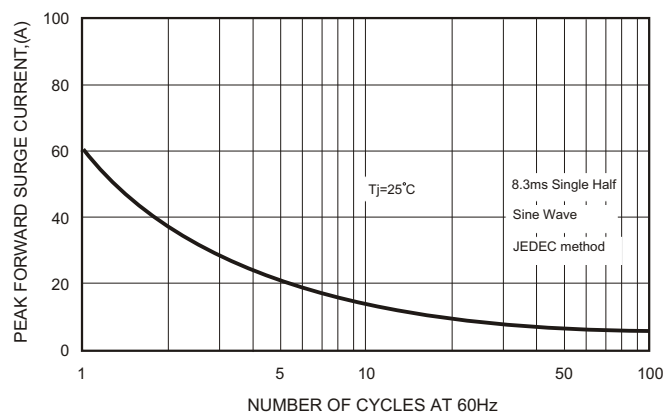


FIG.3 - TYPICAL REVERSE CHARACTERISTICS

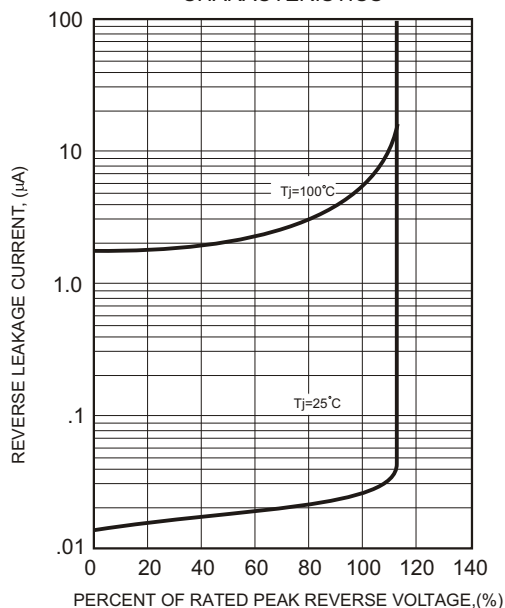


FIG.5-TYPICAL JUNCTION CAPACITANCE

